NSN 5961-01-248-6925



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-248-6925 **Inclosure Material:** Metal **Overall Length:** 1.803 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 breakdown voltage, collector-to-base, emitter open and 150.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and 15.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current and 10.00 amperes source cutoff current blank **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 10001-3151216 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

No Fiig:

Demilitarization:

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